NSN 5961-01-626-6365

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View Online at https://aerobasegroup.com/nsn/5961-01-626-6365 **Inclosure Material:** Ceramic **Overall Length:** Between 0.790 inches and 0.810 inches **Terminal Length:** Between 0.215 inches and 0.255 inches **Overall Height:** Between 0.125 inches and 0.175 inches **Overall Width:** Between 0.650 inches and 0.750 inches **Function For Which Designed:** Amplifier and switching **Mounting Facility Quantity: Mounting Method:** Unthreaded hole Field Force Effect Type: Magnetic field **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 28.0 forward voltage, dc **Current Rating Per Characteristic:** 250.0 milliamperes forward current, dc **Power Rating Per Characteristic:** 45.0 watts power output **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Product Name:** Sd57045 rf power transmitter, in channel enhancement-mode lateral mosfet **Special Features:** Storage temp m65 degrees c to 200 degrees c **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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